

PHOTOCOUPLERS

PS2633, PS2634, PS2633L, PS2634L

HIGH ISOLATION VOLTAGE HIGH COLLECTOR TO EMITTER VOLTAGE DARLINGTON TYPE 6 PIN PHOTOCOUPLER

- NEPOC Series -

DESCRIPTION

PS2633, PS2634 and PS2633L, PS2634L are optically coupled isolators containing a GaAs light emitting diode and an NPN silicon darlington-connected phototransistor.

PS2633, PS2634 are in a plastic DIP (Dual In-line Package).

PS2633L, PS2634L are lead bending type (Gull-wing) for surface mount.

PS2633, PS2633L have base pin and PS2634, PS2634L have no base pin.

FEATURES

- High isolation voltage (BV: 5 kVr.m.s. MIN.)
- High collector to emitter voltage (VcEo: 300 V MIN.)
- Ultra High current transfer ratio (CTR: 1 000 % MIN.)
- High speed switching (t_r, t_f = 100 μ s TYP.)
- UL recognized [File No. E72422(S)]
- Taping product name (PS2633L-E3, E4, PS2634L-E3, E4)

APPLICATIONS

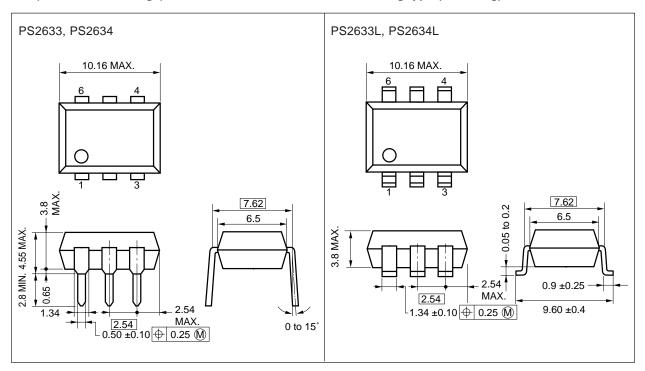
- Telephone/Telegraph line receiver
- Power Supply



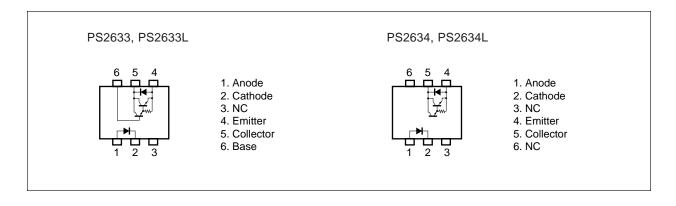
PACKAGE DIMENSIONS (Unit: mm)

DIP (Dual In-line Package)

Lead Bending type (Gull-wing)



PIN CONNECTION (Top View)





ABSOLUTE MAXIMUM RATINGS (TA = 25 $^{\circ}$ C)

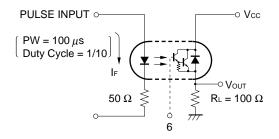
Diode			
			.,
Reverse Voltage	VR	6	V
Forward Current (DC)	lF	80	mA
Power Dissipation Derating	$\Delta P_D/^{\circ}C$	1.5	mW/°C
Power Dissipation	PD	150	mW
Peak Forward Current	F(Peak)	1	Α
(PW = 100 μ s, Duty Cycle 1 %)			
Transistor			
Collector to Emitter Voltage	VCEO	300	V
Emitter to Collector Voltage	Veco	0.6	V
Collector Current	Ic	150	mA
Power Dissipation Derating	$\Delta Pc/^{\circ}C$	3.0	mW/°C
Power Dissipation	Pc	300	mW
Coupled			
Isolation Voltage *1)	BV	5 000	$V_{r.m.s.}$
Storage Temperature	Tstg	-55 to +150	°C
Operating Temperature	Topt	-55 to +100	°C

^{*1)} AC voltage for 1 minute at T_A = 25 °C, RH = 60 % between input (Pin No. 1, 2, 3, Common) and output (Pin No. 4, 5, 6 Common).

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

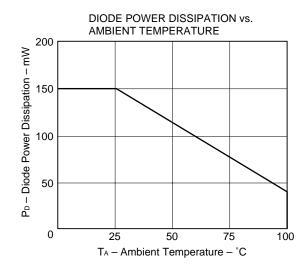
	CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Diode	Forward Voltage	VF		1.15	1.4	V	IF = 10 mA
	Reverse Current	lR			5	μΑ	V _R = 5 V
	Junction Capacitance	Ct		30		pF	V = 0, f = 1.0 MHz
Transistor	Collector to Emitter Dark Current	Iceo			400	nA	Vce = 300 V, I _F = 0
Coupled	Current Transfer Ratio	CTR	1 000	4 000	15 000	%	IF = 1 mA, VcE = 2 V
	Collector Saturation Voltage	VcE(sat)			1.0	V	I _F = 1 mA, I _C = 2 mA
	Isolation Resistance	R ₁₋₂	10 ¹¹			Ω	Vin-out = 1.0 kVpc
	Isolation Capacitance	C ₁₋₂		0.6		pF	V = 0, f = 1.0 MHz
	Rise Time*2)	tr		100		μs	Vcc = 5 V, Ic = 10 mA, RL = 100 Ω
	Fall Time*2)	tf		100		μs	$Vcc = 5 \text{ V}, \text{ Ic} = 10 \text{ mA}, \text{ RL} = 100 \Omega$

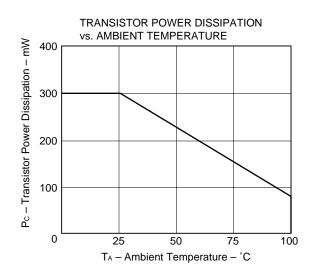
*2) Test Circuit for Switching Time

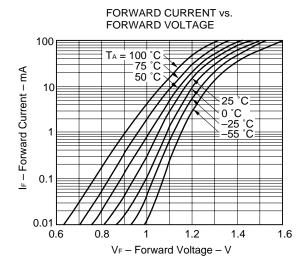


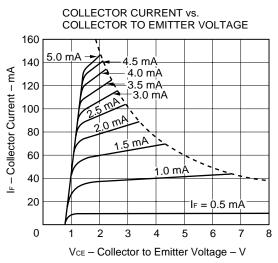


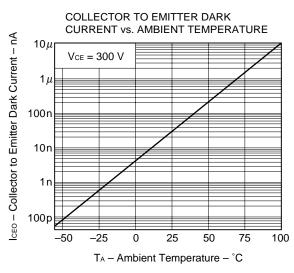
TYPICAL CHARACTERISTICS (TA = 25 °C)

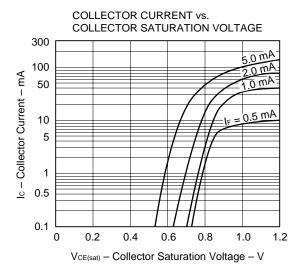


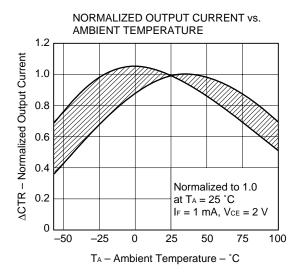


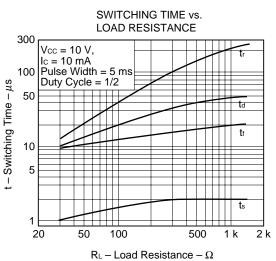


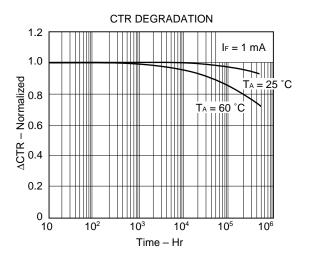


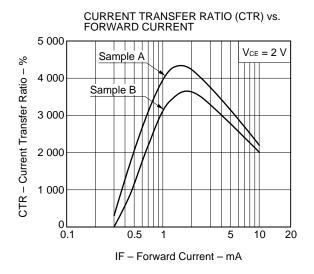


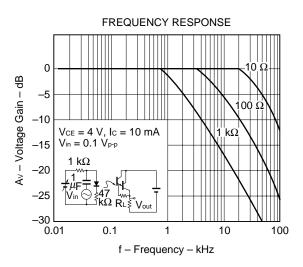












★ The measurement of TYPICAL CHARACTERISTICS are only for reference, not guaranteed.



SOLDERING PRECAUTION

(1) Infrared reflow soldering

• Peak reflow temperature : 235 °C or below (Plastic surface temperature)

• Reflow time : 30 seconds or less

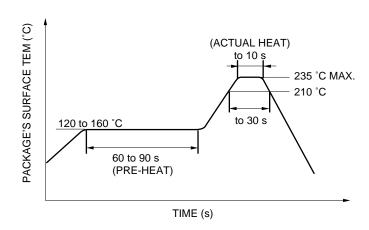
(Time period during which the plastic surface temperature is 210 °C)

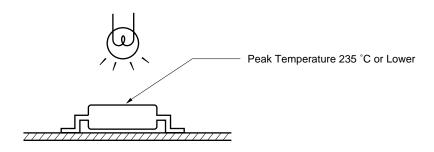
• Number of reflow processes : Three

Flux : Rosin flux containing small amount of chlorine

(The flux with a maximum chlorine content of 0.2 Wt % is recommended.)

INFRARED RAY REFLOW TEMPERATURE PROFILE





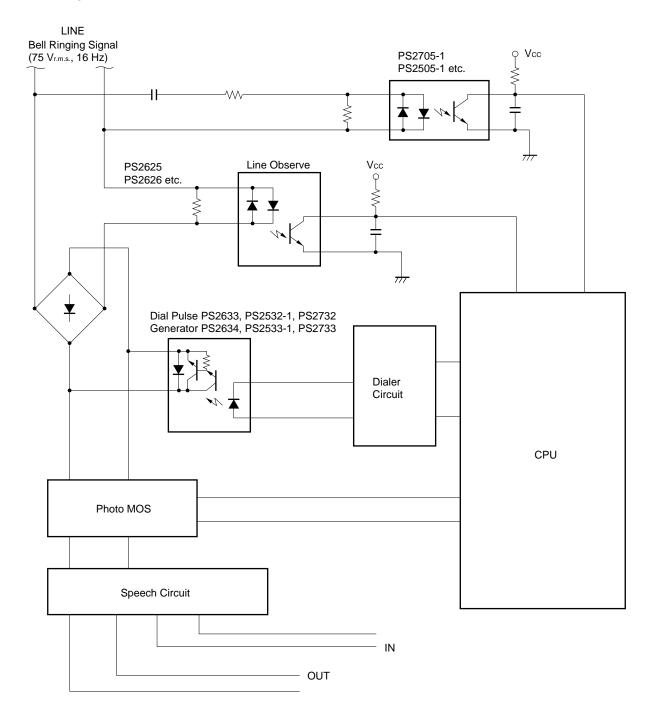
(2) Dip soldering

Peak temperature : 260 °C or lower
 Time : 10 s or less
 Flux : Rosin-base flux



APPLICATIONS OF PHOTO COUPLERS

TELEPHONE





Caution

The Great Care must be taken in dealing with the devices in this guide.

The reason is that the material of the devices is GaAs (Gallium Arsenide), which is designated as harmful substance according to the law concerned.

Keep the law concerned and so on, especially in case of removal.

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Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.

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